

View Online at <https://aerobasegroup.com/nsn/5962-01-374-0093>

Maximum Power Dissipation Rating:

1.04 watts

Operating Temperature Range:

-55.0/+125.0 degrees celsius

Storage Temperature Range:

-65.0/+150.0 degrees celsius

End Application:

Valve-selecti e/i fscm 70339

Features Provided:

Bipolar and programmed and radiation hardened and schottky

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Bipolar metal-oxide semiconductor

Criticality Code Justification:

Feat

Case Outline Source And Designator:

D-3 mil-m-38510

Current Rating Per Characteristic:

100.00 milliamperes reverse current, dc

Terminal Surface Treatment:

Solder

Product Name:

Microcircuit memory 32k prom

Voltage Rating And Type Per Characteristic:

-0.3 volts total supply and 7.0 volts total supply

Time Rating Per Characteristic:

40.00 nanoseconds af output megawatts

Memory Device Type:

Prom

Hybrid Technology Type:

Monolithic

Special Features:

Nuclear hardness critical item

Test Data Document:

81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). And 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

24 printed circuit

Specification Data:

67268-8200803ia government standard and 03640-123a879-4 manufacturers source control

Departure From Cited Designator:

Altered by programming & marking

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fig:

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